SDAS040B - DECEMBER 1983 - REVISED JANUARY 1995

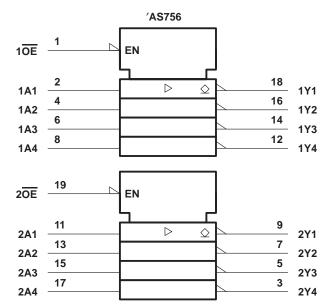
- Open-Collector Outputs Drive Bus Lines or Buffer Memory Address Registers
- Eliminate the Need for 3-State Overlap Protection
- pnp Inputs Reduce dc Loading
- Open-Collector Versions of 'AS240A and 'AS241
- Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

#### description

These octal buffers and line drivers are designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters by eliminating the need for 3-state overlap protection. The designer has a choice of selected combinations of inverting and noninverting outputs, symmetrical active-low output-enable ( $\overline{OE}$ ) inputs, and complementary OE and  $\overline{OE}$  inputs. These devices feature high fan-out and improved fan-in.

The SN54AS756 is characterized for operation over the full military temperature range of  $-55^{\circ}$ C to 125°C. The SN74AS756 and SN74AS757 are characterized for operation from 0°C to 70°C.

#### logic symbols<sup>‡</sup>

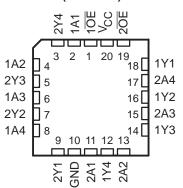


JU, JII <i>I 47</i>	TOP VI		
,			
10E [		20	] v <sub>cc</sub>
1A1 [	2	19	20E/20E <sup>†</sup>
2Y4 [	3	18	] 1Y1
1A2 [	4	17	] 2A4
2Y3 [	5	16	] 1Y2
1A3 [	6	15	] 2A3
2Y2 [	7	14	] 1Y3
1A4 [	8	13	] 2A2
2Y1 [	9	12	] 1Y4
GND [	10	11	] 2A1

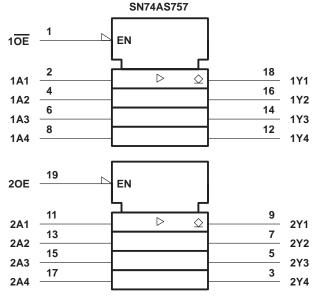
SN54AS756 ... J PACKAGE

SN74AS756, SN74AS757 ... DW OR N PACKAGE

SN54AS756 ... FK PACKAGE (TOP VIEW)



<sup>†</sup> 20E for 'AS756 or 20E for SN74AS757



<sup>‡</sup> These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

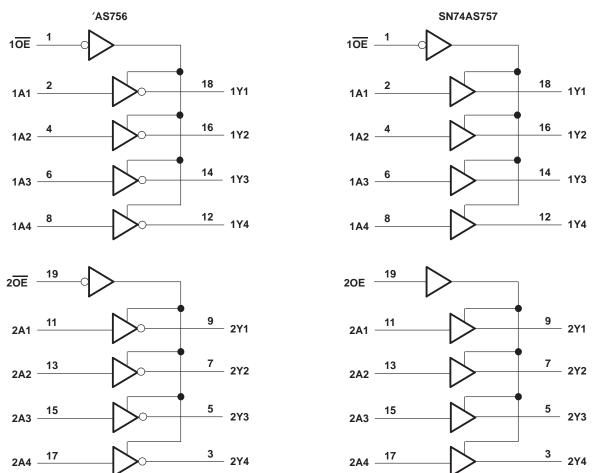


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#### logic diagrams (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage, V <sub>CC</sub>		
Input voltage, V <sub>1</sub>		
Off-state output voltage		
Operating free-air temperature range, TA:	SN54AS756	–55°C to 125°C
	SN74AS756, SN74AS757	0°C to 70°C
Storage temperature range		–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



SDAS040B - DECEMBER 1983 - REVISED JANUARY 1995

#### recommended operating conditions

		SI	154AS75	6	SN74AS756 SN74AS757			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
VCC	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
$V_{ L}$	Low-level input voltage			0.7			0.8	V
VOH	High-level output voltage			5.5			5.5	V
IOL	Low-level output current			48			64	mA
TA	Operating free-air temperature	-55		125	0		70	°C

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST	TEST CONDITIONS			56	SN74AS756 SN74AS757			UNIT	
				MIN	TYP <sup>†</sup>	MAX	MIN	TYP <sup>†</sup>	MAX		
VIK		V <sub>CC</sub> = 4.5 V,	lj = – 18 mA			-1.2			-1.2	V	
IOH		V <sub>CC</sub> = 4.5 V,	V <sub>OH</sub> = 5.5 V			0.1			0.1	mA	
			I <sub>OL</sub> = 48 mA			0.55					
VOL		$V_{CC} = 4.5 V$	IOL = 64 mA						0.55	V	
Ц		V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 7 V			0.1			0.1	mA	
Iн		V <sub>CC</sub> = 5.5 V,	VI = 2.7 V			20			20	μA	
ЦL	A inputs of SN74AS757 only	V <sub>CC</sub> = 5.5 V,	V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 0.4 V			-1			-1	mA	
	All other inputs		·			-0.5			-0.5		
	(4.0750		Outputs high		9	15		9	15		
	'AS756	$V_{CC} = 5.5 V$	Outputs low		51	80		51	80		
'CC			Outputs high		21 33 21 33				33	mA	
	SN74AS757	V <sub>CC</sub> = 5.5 V	Outputs low		61	95		61	95		

<sup>†</sup> All typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> =  $25^{\circ}$ C.



SDAS040B - DECEMBER 1983 - REVISED JANUARY 1995

#### switching characteristics (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 4.5 V to 5.5 V, C <sub>L</sub> = 50 pF, R <sub>L</sub> = 500 Ω, T <sub>A</sub> = MIN to MAX <sup>†</sup>		мах†			
	(	(,	SN54A	AS756	SN74AS756			
			MIN	MAX	MIN	MAX		
<sup>t</sup> PLH	A		3	20	3	19		
<sup>t</sup> PHL		Y	1	7	1	6	ns	
<sup>t</sup> PLH	OE	V	3	22	3	19.5	200	
<sup>t</sup> PHL	UE UE	ŕ	1	8.5	1	7.5	ns	

<sup>†</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

#### switching characteristics (see Figure 1)

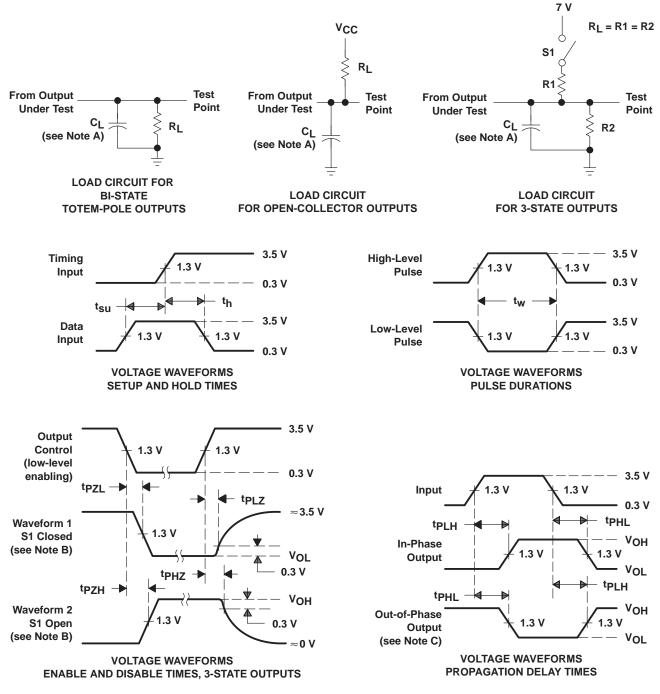
PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 4.5$ $C_L = 50 \text{ pF}$ $R_L = 500 \Omega$ $T_A = \text{MIN tr}$ SN74/ MIN	<u>o</u> , o MAX†	UNIT
<sup>t</sup> PLH			3	18.5	
<sup>t</sup> PHL	A	Y	1	6	ns
<sup>t</sup> PLH	1 <mark>0E</mark>		3	20	
<sup>t</sup> PHL	10E	1Y	1	7	ns
tPLH	20E	2Y	3	21	20
<sup>t</sup> PHL	20E	ZŤ	1	7.5	ns

<sup>†</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.



#### SN54AS756, SN74AS756, SN74AS757 OCTAL BUFFERS AND LINE DRIVERS WITH OPEN-COLLECTOR OUTPUTS SDAS040B - DECEMBER 1983 - REVISED JANUARY 1995

PARAMETER MEASUREMENT INFORMATION SERIES 54ALS/74ALS AND 54AS/74AS DEVICES



NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. When measuring propagation delay items of 3-state outputs, switch S1 is open.
- D. All input pulses have the following characteristics: PRR  $\leq$  1 MHz, t<sub>f</sub> = t<sub>f</sub> = 2 ns, duty cycle = 50%.
- E. The outputs are measured one at a time with one transition per measurement.

#### Figure 1. Load Circuits and Voltage Waveforms





#### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-90563012A	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 90563012A SNJ54AS 756FK	Samples
5962-9056301RA	ACTIVE	CDIP	J	20	20	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9056301RA SNJ54AS756J	Samples
5962-9056301SA	ACTIVE	CFP	W	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9056301SA SNJ54AS756W	Samples
SN54AS756J	ACTIVE	CDIP	J	20	20	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	SN54AS756J	Samples
SN74AS756DW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	AS756	Samples
SN74AS756N	ACTIVE	PDIP	N	20	20	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	0 to 70	SN74AS756N	Samples
SN74AS757DW	LIFEBUY	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	AS757	
SN74AS757DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	AS757	Samples
SN74AS757N	ACTIVE	PDIP	N	20	20	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	0 to 70	SN74AS757N	Samples
SNJ54AS756FK	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 90563012A SNJ54AS 756FK	Samples
SNJ54AS756J	ACTIVE	CDIP	J	20	20	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9056301RA SNJ54AS756J	Samples
SNJ54AS756W	ACTIVE	CFP	W	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9056301SA SNJ54AS756W	Samples

<sup>(1)</sup> The marketing status values are defined as follows: ACTIVE: Product device recommended for new designs. LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.



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### PACKAGE OPTION ADDENDUM

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF SN54AS756, SN74AS756 :

• Catalog : SN74AS756

• Military : SN54AS756

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications



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#### **TAPE AND REEL INFORMATION**





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal					
Device	Package	Package	Pins	SPQ	Ree
	Typo	Drawing			Diam

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AS757DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1



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## PACKAGE MATERIALS INFORMATION

9-Aug-2022



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AS757DWR	SOIC	DW	20	2000	367.0	367.0	45.0

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#### TUBE



#### - B - Alignment groove width

#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
5962-90563012A	FK	LCCC	20	1	506.98	12.06	2030	NA
5962-9056301SA	W	CFP	20	1	506.98	26.16	6220	NA
SN74AS756DW	DW	SOIC	20	25	507	12.83	5080	6.6
SN74AS756N	N	PDIP	20	20	506	13.97	11230	4.32
SN74AS757DW	DW	SOIC	20	25	507	12.83	5080	6.6
SN74AS757N	N	PDIP	20	20	506	13.97	11230	4.32
SNJ54AS756FK	FK	LCCC	20	1	506.98	12.06	2030	NA
SNJ54AS756W	W	CFP	20	1	506.98	26.16	6220	NA

W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



- NOTES: A. All linear dimensions are in inches (millimeters).
  - This drawing is subject to change without notice. В.
  - C. This package can be hermetically sealed with a ceramic lid using glass frit.
    D. Index point is provided on cap for terminal identification only.
    E. Falls within Mil-Std 1835 GDFP2-F20



## FK 20

#### 8.89 x 8.89, 1.27 mm pitch

## **GENERIC PACKAGE VIEW**

### LCCC - 2.03 mm max height

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





### N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- $\triangle$  The 20 pin end lead shoulder width is a vendor option, either half or full width.



# **DW0020A**



## **PACKAGE OUTLINE**

#### SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



# DW0020A

# **EXAMPLE BOARD LAYOUT**

### SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



## DW0020A

# **EXAMPLE STENCIL DESIGN**

### SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



J (R-GDIP-T\*\*) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

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